VS-25F(R) Series

Vishay Semiconductors



Standard Recovery Diodes, (Stud Version), 25 A



PRIMARY CHARACTERISTICS				
I _{F(AV)} 25 A				
Package DO-4 (DO-203AA)				
Circuit configuration Single				

FEATURES

- High surge current capability
- · Stud cathode and stud anode version
- Wide current range
- Types up to 1200 V V_{RRM}
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		25	А	
	T _C	120	°C	
I _{F(RMS)}		40	А	
I _{FSM}	50 Hz	356	٨	
	60 Hz	373	A	
l ² t	50 Hz	636	A ² s	
	60 Hz	580	A-S	
V _{RRM}	Range	100 to 1200	V	
TJ		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 175 °C mA	
	10	100	150		
	20	200	275		
	40	400	500		
VS-25F(R)	60	600	725	12	
	80	800	950		
	100	1000	1200		
	120	1200	1400		

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	180° conduction, half sine wave		25	А	
at case temperature	·r(AV)				120	°C
Maximum RMS forward current	I _{F(RMS)}				40	А
		t = 10 ms	No voltage		356	
Maximum peak, one-cycle forward,	I	t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = T _J maximum	373	A
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		300	A
		t = 8.3 ms	reapplied		314	
	l ² t	t = 10 ms	No voltage reapplied		636	A ² s
Maximum I ² t for fusing		t = 8.3 ms			580	
		t = 10 ms	100 % V _{RRM} reapplied		450	
		t = 8.3 ms			410	
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		6360	A²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.80		
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J$ maximum			0.90	V
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum			6.80	m 0
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$			5.70	mΩ
Maximum forward voltage drop	V _{FM}	I_{pk} = 78 A, T_J = 25 °C, t_p = 400 µs rectangular wave			1.30	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating temperature range	TJ		-65 to +175	°C	
Maximum storage temperature range	T _{Stg}		-65 to +200	U	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5		
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5	K/W	
		Not lubricated threads	1.5 + 0 - 10 % (13)	N · m (lbf · in)	
Allowable mounting torque		Lubricated threads	1.2 + 0 - 10 % (10)	N · m (lbf · in)	
Approximate weight			7	g	
			0.25	oz.	
Case style		See dimensions - link at the end of datasheet	DO-4 (DO-	-203AA)	

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.28	0.24			
120°	0.39	0.41			
90°	0.50	0.54	$T_J = T_J maximum$	K/W	
60°	0.73	0.75			
30°	1.20	1.21			

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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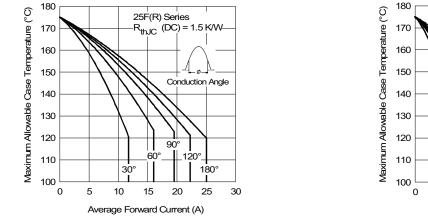


Fig. 1 - Current Ratings Characteristics

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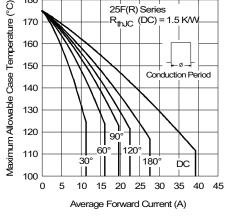


Fig. 2 - Current Ratings Characteristics

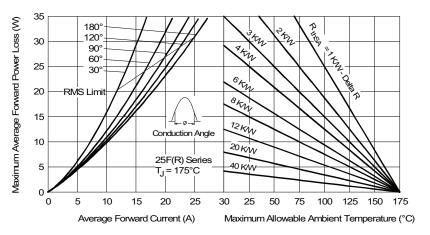
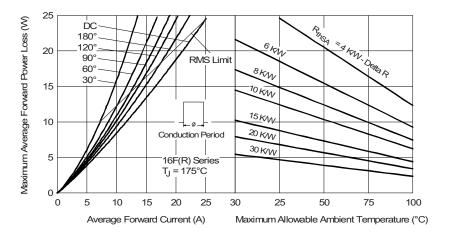
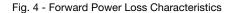


Fig. 3 - Forward Power Loss Characteristics







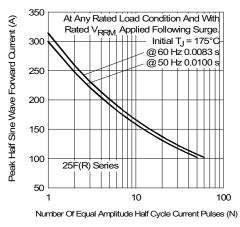


Fig. 5 - Maximum Non-Repetitive Surge Current

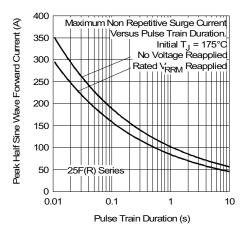
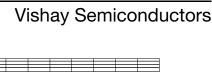


Fig. 6 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE



VS-25F(R) Series

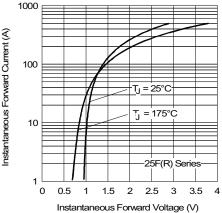


Fig. 7 - Forward Voltage Drop Characteristics

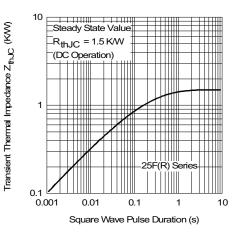
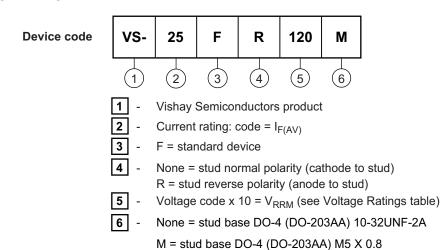


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95311				
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R 0.40 R (0.02)

Ø 6.8 (0.27)

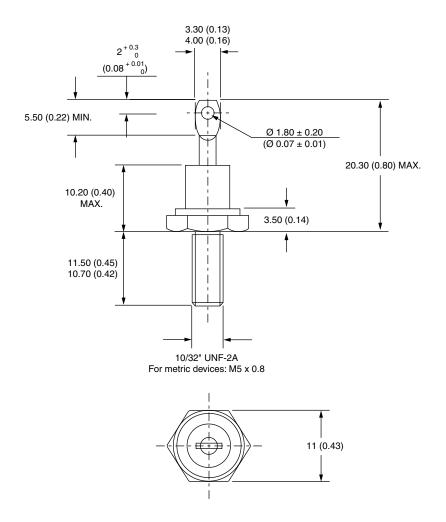
 0.8 ± 0.1

 (0.03 ± 0.004)



DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)







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